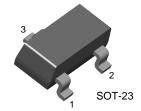


KST3906

General Purpose Transistor



PNP Epitaxial Silicon Transistor

1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings T_a=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|-----------------------------|-------|-------|
| V_{CBO} | Collector-Base Voltage | -40 | V |
| V _{CEO} | Collector-Emitter Voltage | -40 | V |
| V_{EBO} | Emitter-Base Voltage | -5 | V |
| I _C | Collector Current | -200 | mA |
| P _C | Collector Power Dissipation | 350 | mW |
| T _{STG} | Storage Temperature | 150 | °C |

Electrical Characteristics T_a =25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Max. | Units |
|-----------------------|--|--|-----------------------------|----------------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_{C} = -10\mu A, I_{E} = 0$ | -40 | | V |
| BV _{CEO} | * Collector-Emitter Breakdown Voltage | I _C = -1.0mA, I _B =0 | -40 | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I _E =10μA, I _C =0 | -5 | | V |
| I _{CEX} | Collector Cut-off Current | V _{CE} = -30V, V _{EB} = -3V | | -50 | nA |
| h _{FE} | * DC Current Gain | V_{CE} = -1V, I_{C} = -0.1mA V_{CE} = -1V, I_{C} = -1mA V_{CE} = -1V, I_{C} = -10mA V_{CE} = -1V, I_{C} = -50mA V_{CE} = -1V, I_{C} = -100mA | 60 80 100 60 30 | 300 | |
| V _{CE} (sat) | * Collector-Emitter Saturation Voltage | I _C = -10mA, I _B = -1mA I _C = -50mA, I _B = -5.0mA | | -0.25 -0.4 | V |
| V _{BE} (sat) | * Base-Emitter Saturation Voltage | I _C = -10mA, I _B = -1.0mA I _C = -50mA, I _B = -5.0mA | -0.65 | -0.85 -0.95 | V |
| f _T | Current Gain Bandwidth Product | I _C = -10mA, V _{CE} = -20V f=100MHz | 250 | | MHz |
| C _{ob} | Output Capacitance | V _{CB} = -5V, I _E =0, f=1.0MHz | | 4.5 | pF |
| NF | Noise Figure | I_C = -100μA, V_{CE} = -5V R_S =1KΩ f =10Hz to 15.7KHz | | 4 | dB |
| t _{ON} | Turn On Time | V_{CC} = -3V, V_{BE} = -0.5V I_{C} = -10mA, I_{B1} = -1mA | | 70 | ns |
| t _{OFF} | Turn Off Time | V_{CC} = -3V, I_{C} = -10mA I_{B1} = I_{B2} = -1mA | | 300 | ns |

^{*} Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%



Typical Characteristics

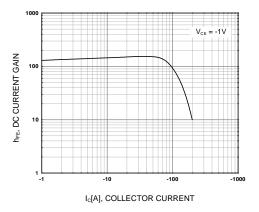


Figure 1. DC current Gain

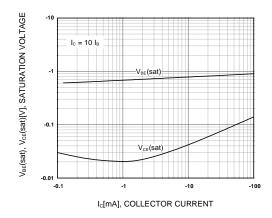


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

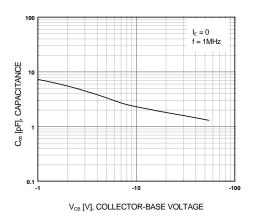


Figure 3. Output Capacitance

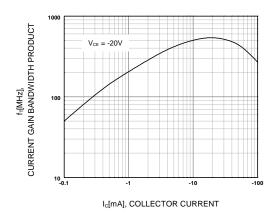
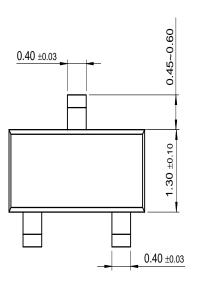
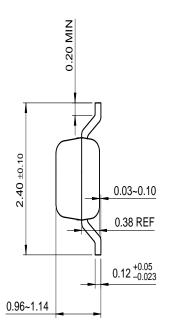


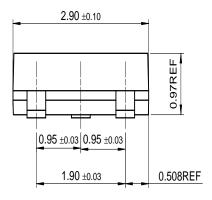
Figure 4. Current Gain Bandwidth Product

Package Demensions

SOT-23







Dimensions in Millimeters

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